

SK6681 5.5V 1A 1.5MHz Sync Constant Current LED Driver

General Description

The SK6681 is a 1A constant current LED driver designed to provide a simple, high efficiency solution for driving high power LEDs. With a 100mV reference voltage feedback control to minimize power dissipation, an external resistor sets the current as needed for driving various types of LEDs. Supply current with no load is 40uA and drops to <math><1\mu\text{A}</math> in shutdown. The 2.5V to 5.5V input voltage range makes the SK6681 ideally suited for single Li-Ion battery powered applications. 100% duty cycle provides low dropout operation, extending battery life in portable systems. PWM/PFM mode operation provides very low output ripple voltage for noise sensitive applications. Switching frequency is internally set at 1.5MHz, allowing the use of small surface mount inductors and capacitors. Additional features include user accessible CTRL pin for enabling and PWM dimming of LEDs, thermal shutdown, cycle-by-cycle current limit and overcurrent protection. The SK6681 requires a minimal number of readily available, external components and is available in a space saving SOT23-5 package.

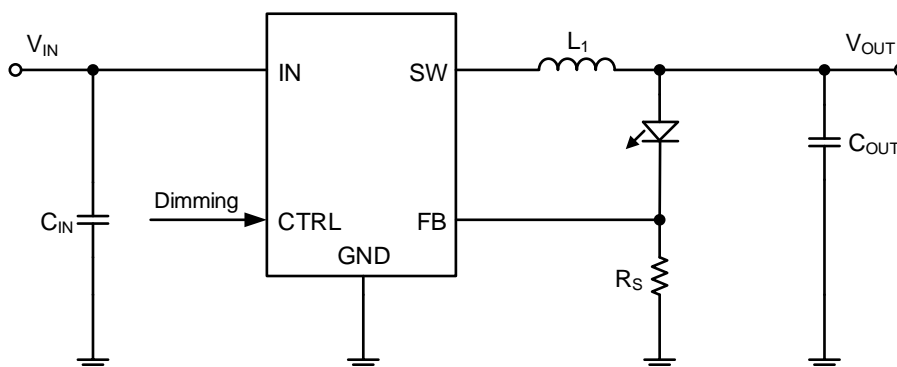
Features

- 2.5V to 5.5V Input Voltage Range
- 1A Continuous Output Current
- 1.5MHz Switching Frequency
- LED Open Load Protection
- Built-in Over Current Limit
- Input Over Voltage Protection
- PFM Mode for High Efficiency in Light Load
- Internal Soft-Start
- PWM Brightness Control on Enable
- 100mV Low Feedback Voltage
- No Schottky Diode Required
- Over Temperature Protected
- Low Quiescent Current: 40uA
- LED Short Protection
- Available in SOT23-5 package
- -40°C to +85°C Temperature Range

Applications

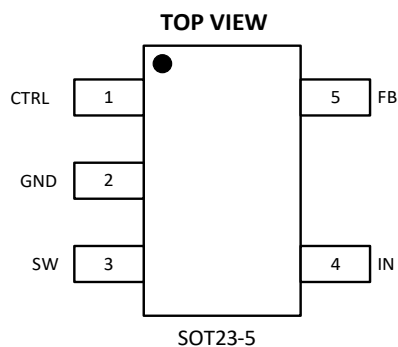
- LED Drivers
- Industrial Lighting
- LED Flashlights
- Digital Still and Video Cameras

Typical Application Circuit



Basic Application Circuit

Pin Configuration



Pin Description

Pin	Name	Function
1	CTRL	CTRL pin is a multi-functional pin which can be used for enable control and PWM dimming. Should not be left floating.
2	GND	Ground Pin
3	SW	Power Switch Output. It is the switch node connection to Inductor. This pin connects to the drains of the internal P-ch and N-ch MOSFET switches.
4	IN	Power Supply Input. Must be closely decoupled to GND with a 22 μ F or greater ceramic capacitor.
5	FB	Feedback Reference Voltage Pin. Series connect a resistor R_S between LED and ground as a current sense. Sense the current feedback voltage to set the current rating.

Ordering Information

Part Number	Package	Mark	Quantity/ Reel
SK6681	SOT23-5	JMXXX	3000

SK6681 devices are Pb-free and RoHS compliant.

Absolute Maximum Ratings ^{(1) (2)}

Item	Min	Max	Unit
V _{IN} voltage	-0.3	6	V
EN voltage	-0.3	6	V
SW voltage	-0.3	6.3	V
SW voltage (10ns transient)	-5	8	V
FB voltage	-0.3	6	V
Power dissipation ⁽³⁾	Internally Limited		
Operating junction temperature, T _J	-40	150	°C
Storage temperature, T _{stg}	-55	150	°C
Lead Temperature (Soldering, 10sec.)		260	°C

Note (1): Exceeding these ratings may damage the device.

Note (2): The device is not guaranteed to function outside of its operating conditions.

Note (3): The maximum allowable power dissipation is a function of the maximum junction temperature, T_{J(MAX)}, the junction-to-ambient thermal resistance, R_{θJA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: P_{D(MAX)} = (T_{J(MAX)} - T_A)/R_{θJA}. Exceeding the maximum allowable power dissipation causes excessive die temperature, and the regulator goes into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Thermal shutdown engages at T_J=160°C (typical) and disengages at T_J=130°C (typical).

ESD Ratings

Item	Description	Value	Unit
V _(ESD-HBM)	Human Body Model (HBM) ANSI/ESDA/JEDEC JS-001-2014 Classification, Class: 2	±2000	V
V _(ESD-CDM)	Charged Device Mode (CDM) ANSI/ESDA/JEDEC JS-002-2014 Classification, Class: C0b	±200	V
I _{LATCH-UP}	JEDEC STANDARD NO.78E APRIL 2016 Temperature Classification, Class: I	±150	mA

Recommended Operating Conditions

Item	Min	Max	Unit
Operating junction temperature ⁽¹⁾	-40	125	°C
Operating temperature range	-40	85	°C
Input voltage V _{IN}	2.5	5.5	V
Output current	0	1	A

Note (1): All limits specified at room temperature (T_A = 25°C) unless otherwise specified. All room temperature limits are 100% production tested. All limits at temperature extremes are ensured through correlation using standard Statistical Quality Control (SQC) methods. All limits are used to calculate Average Outgoing Quality Level (AOQL).

Thermal Information

Item	Description	Value	Unit
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾⁽²⁾	180	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	130	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	45	°C/W
ψ_{JT}	Junction-to-top characterization parameter	35	°C/W
ψ_{JB}	Junction-to-board characterization parameter	45	°C/W

Note (1): The package thermal impedance is calculated in accordance to JESD 51-7.

Note (2): Thermal Resistances were simulated on a 4-layer, JEDEC board

Electrical Characteristics ⁽¹⁾⁽²⁾

$V_{IN}=5V$, $T_A=25^{\circ}C$, unless otherwise specified.

Parameter	Conditions	Min.	Typ.	Max.	Unit
Input Voltage Range		2.5		5.5	V
Supply Current (Quiescent)	$V_{CTRL} = High$, $V_{FB}=110\%$		40	80	μA
Supply Current (Shutdown)	$V_{CTRL} = 0$ or $CTRL = GND$		0.1	1.0	μA
Feedback Voltage		0.097	0.100	0.103	V
High-Side Switch On-Resistance	$I_{SW}=100mA$		300		m Ω
Low-Side Switch On-Resistance	$I_{SW}=-100mA$		200		m Ω
Upper Switch Current Limit		2			A
Over Voltage Protection Threshold			6		V
Switching Frequency			1.5		MHz
Maximum Duty Cycle	$V_{FB}=90\%$		100		%
CTRL Rising Threshold		2.5			V
CTRL Falling Threshold				0.8	V
Under-Voltage Lockout Threshold	Wake up V_{IN} Voltage		2.3	2.45	V
	Shutdown V_{IN} Voltage	1.75	1.9		V
	Hysteresis V_{IN} voltage		400		mV
Soft Start			1		mS
Thermal Shutdown			160		°C
Thermal Hysteresis			30		°C

Note (1): MOSFET on-resistance specifications are guaranteed by correlation to wafer level measurements.

Note (2): Thermal shutdown specifications are guaranteed by correlation to the design and characteristics analysis.

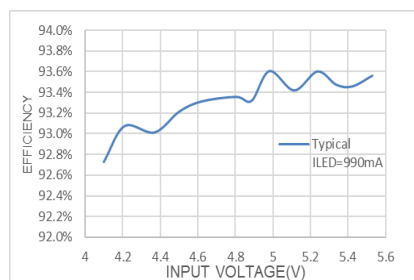
Typical Performance Characteristics ⁽¹⁾⁽²⁾

Note (1): Performance waveforms are tested on the evaluation board.

Note (2): $V_{IN}=5V$, $V_{OUT}=1$ Series 3 Parallel LED, $T_A = +25^{\circ}C$, unless otherwise noted.

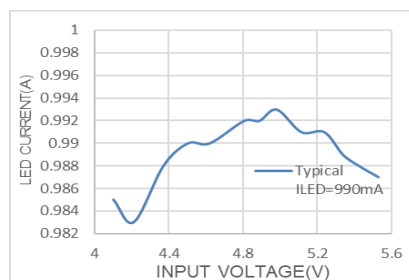
Efficiency vs. Input Voltage

$V_{OUT}=1$ Series 3 Parallel LED



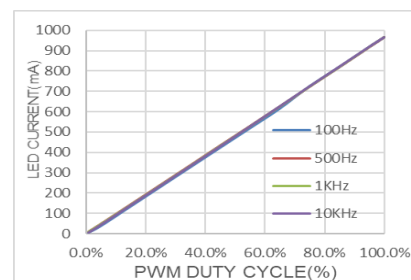
LED Current vs. Input Voltage

$V_{OUT}=1$ Series 3 Parallel LED



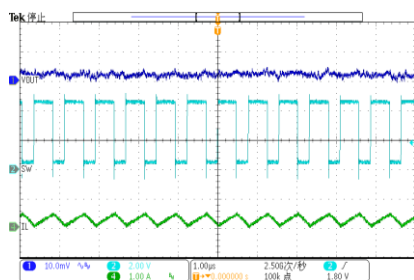
LED Current vs. PWM Duty Cycle

$V_{OUT}=1$ Series 3 Parallel LED



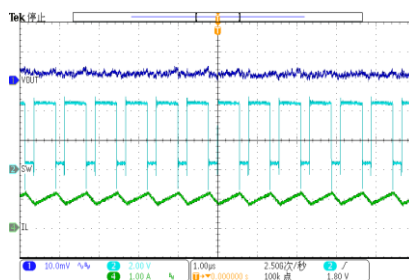
Steady State

$I_{LED}=0.2A$



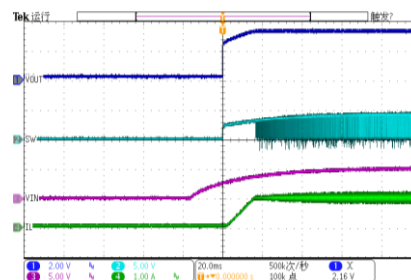
Steady State

$I_{LED}=1A$



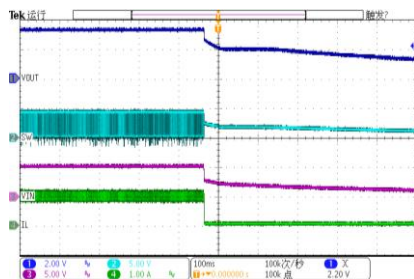
V_{IN} Start-Up

$I_{LED}=1A$



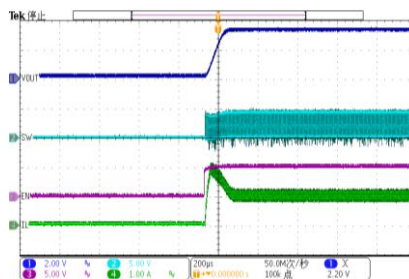
V_{IN} Shut-Down

$I_{LED}=1A$



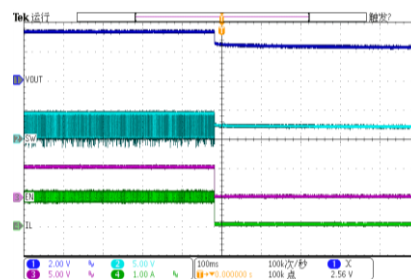
Enable Start-Up

$V_{IN}=5V$, $I_{LED}=1A$



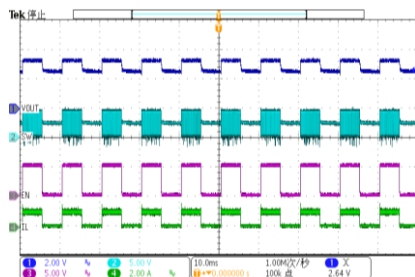
Enable Shut-Down

$V_{IN}=5V$, $I_{LED}=1A$



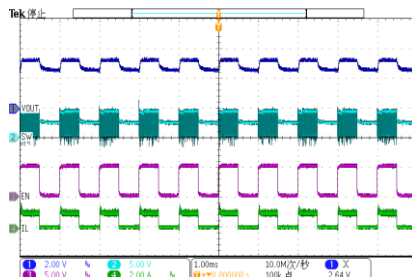
Dimming Operation

$V_{IN}=5V, I_{LED}=1A, f=100Hz$



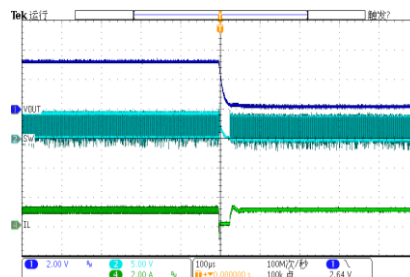
Dimming Operation

$V_{IN}=5V, I_{LED}=1A, f=1KHz$



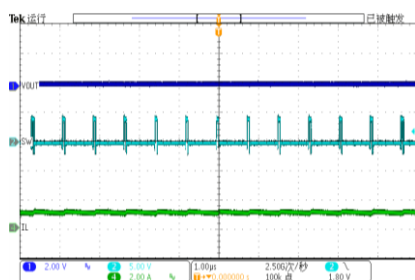
LED+ Short to LED- Entry

$V_{IN}=5V$



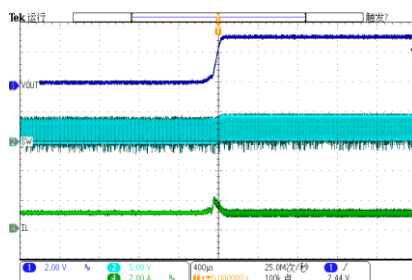
LED+ Short to LED- SteadyState

$V_{IN}=5V$



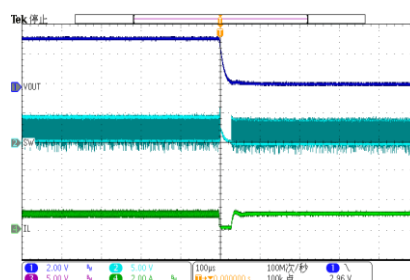
LED+ Short to LED- Recovery

$V_{IN}=5V$



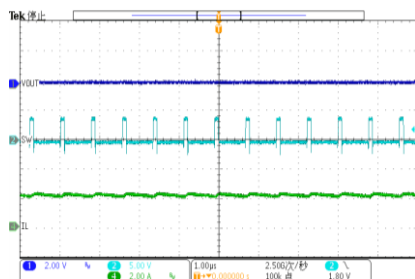
LED+ Short to GND Entry

$V_{IN}=5V$



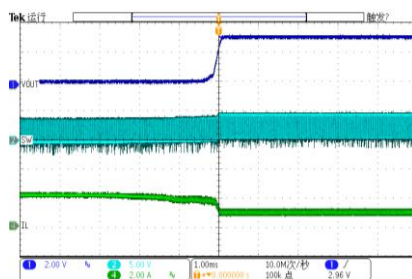
LED+ Short to GND SteadyState

$V_{IN}=5V$



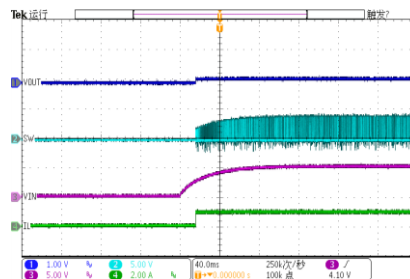
LED+ Short to GND Recovery

$V_{IN}=5V$



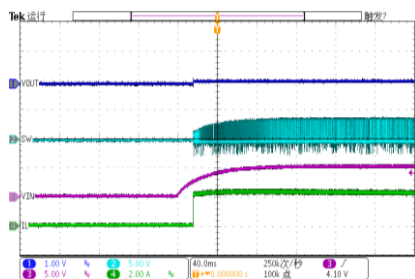
LED+ Short to LED- V_{IN} Up

$V_{IN}=5V$



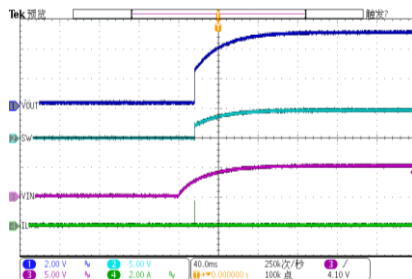
LED+ Short to GND V_{IN} Up

$V_{IN}=5V$

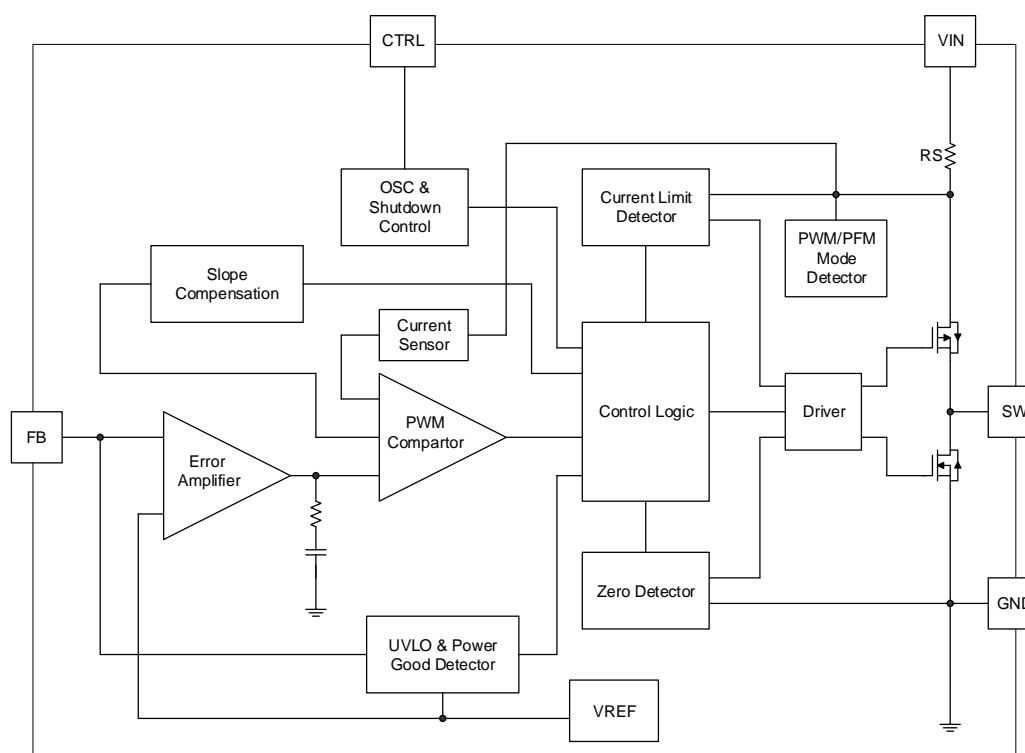


V_{OUT} Open V_{IN} Up

$V_{IN}=5V$



Functional Block Diagram



Block Diagram

Functions Description

Under-Voltage Lockout (UVLO)

Under-voltage lockout (UVLO) protects the chip from operating at an insufficient supply voltage. UVLO protection monitors the internal regulator voltage. When the voltage is lower than UVLO threshold voltage, the device is shut off. When the voltage is higher than UVLO threshold voltage, the device is enabled again.

Enable and PWM Dimming

When the input voltage is above maximal UVLO rising threshold and the CTRL pin is pulled high, the SK6681 is enabled. When the CTRL pin is pulled low, the SK6681 goes into shutdown mode. In shutdown mode, less than 1 μ A input current is consumed. The CTRL pin allows disabling and enabling of the device as well as brightness control of the LEDs by applying a PWM signal up to typically 1kHz. When a PWM signal is applied, the LED current is turned on when the CTRL is high and off when CTRL is pulled low. Changing the PWM duty cycle therefore changes the LED brightness.

Soft-Start

The SK6681 begins soft start when the CTRL pin is pulled high. at the beginning of the soft start period, the isolation FET is turned on slowly to charge the output capacitor. After the pre-charge phase, the SK6681 starts switching. This is called switching soft start phase. An internal soft start circuit limits the peak inductor current according to the output voltage. The switching soft start phase is about 1ms typically. The soft start function reduces the inrush current during startup.

Efficiency and Feedback Voltage

The feedback voltage has a direct effect on the converter efficiency. Because the voltage drop across the feedback resistor does not contribute to the output power (LED brightness), the lower the feedback voltage, the higher the efficiency.

Current Limit

The SK6681 uses cycle-by-cycle current limit to protect the internal power switch. During each switching cycle, a current limit comparator detects if the power switch current exceeds 2A (typical), and turns off the switch until the next switching cycle begins.

Thermal Shutdown

Thermal shutdown prevents the chip from operating at exceedingly high temperatures. When the silicon die temperature exceeds 160°C, it shuts down the whole chip. When the temperature falls below its lower threshold (Typ. 130°C) the chip is enabled again.

Applications Information

Setting the LED Current

The LED current is controlled by the feedback resistor, R_S , in the following table. The current through the LEDs is given by the equation $100\text{mV}/R_S$. Following table shows the selection of resistors for a given LED current.

I_{LED} (A)	R_S (Ω)
0.1	1
0.2	0.5
0.5	0.2
1	0.1

I_{LED} is average LED current.

Dimming Control

For controlling the LED brightness, the SK6681 can perform the dimming control by applying a PWM signal to CTRL pin. The internal soft start and the wide range dimming frequency can eliminate inrush current and audio noise when dimming. The average LED current is proportional to the PWM signal duty cycle. The magnitude of the PWM signal should be higher than the enable voltage of CTRL pin.

Inductor Selection

The recommended value of inductor for most applications are $2.2\mu\text{H}$. Small size and better efficiency are the major concerns for portable device, such as SK6681 used for mobile phone. When selecting the inductor, the inductor saturation current should be rated as high as the peak inductor current at maximum load, and respectively, maximum LED current.

Output Capacitor Selection

The device is designed to operate with a wide selection of ceramic output capacitors. The selection of the output capacitor value is a trade-off between output voltage ripple and capacitor cost and form factor. In general, capacitor values of $22\mu\text{F}$ up to $44\mu\text{F}$ can be used. For better voltage filtering, ceramic capacitors with low ESR are recommended. X5R and X7R types are suitable because of their wider voltage and temperature ranges.

Input Capacitor Selection

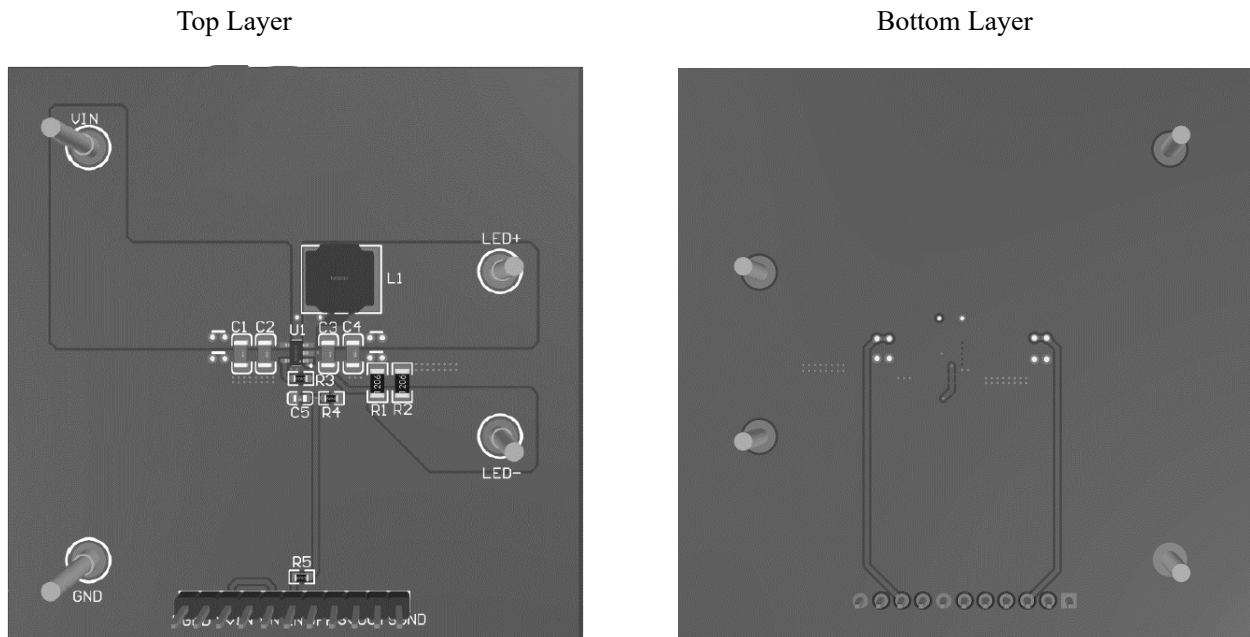
For good input voltage filtering, low ESR ceramic capacitors are recommended. A $22\mu\text{F}$ ceramic input capacitor is sufficient for most of the applications. For better input voltage filtering and EMI reduction, this value can be increased. The input capacitor should be placed as close as possible to the input pin of the converter.

PC Board Layout Consideration

PCB layout is very important to achieve stable operation. It is highly recommended to duplicate EVB layout for optimum performance. If change is necessary, please follow these guidelines for reference.

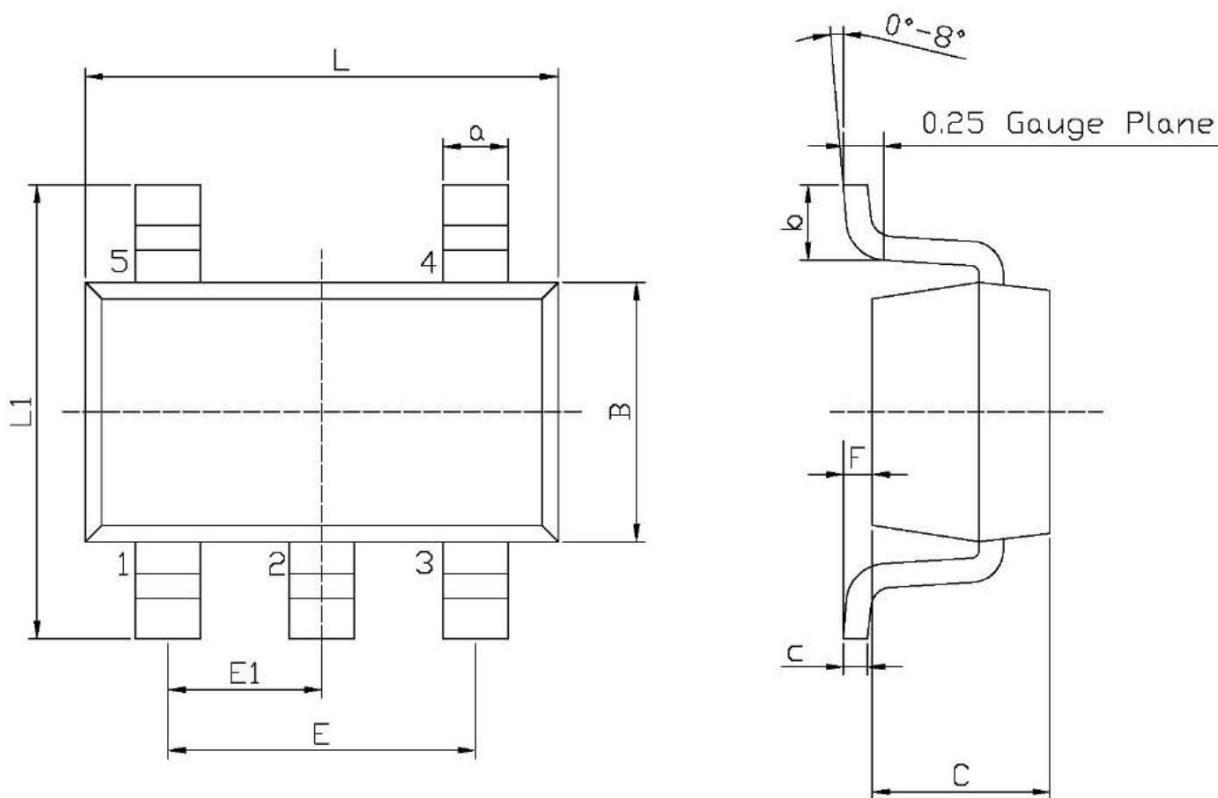
1. Keep the path of switching current short and minimize the loop area formed by Input capacitor, high-side MOSFET and low-side MOSFET.
2. Bypass ceramic capacitors are suggested to be put close to the V_{IN} Pin.
3. Ensure all feedback connections are short and direct. Place the feedback resistors and compensation components as close to the chip as possible.
4. V_{OUT} , SW away from sensitive analog areas such as FB.

Connect IN, SW, and especially GND respectively to a large copper area to cool the chip to improve thermal performance and long-term reliability.



Sample Board Layout

Package Description: SOT23-5



Unit: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
L	2.82	3.02	E1	0.85	1.05
B	1.50	1.70	a	0.35	0.50
C	0.90	1.30	c	0.10	0.20
L1	2.60	3.00	b	0.35	0.55
E	1.80	2.00	F	0	0.15

- Note:**
- 1) All dimensions are in millimeters.
 - 2) Package length does not include mold flash, protrusion or gate burr.
 - 3) Package width does not include inter lead flash or protrusion.
 - 4) Lead popularity (bottom of leads after forming) shall be 0.10 millimeters max.